



**CYPRESS**

**COMLINK™ SERIES**

**CY2CC1810**

## 1:10 Clock Fanout Buffer with Output Enable

### Features

- Low-voltage operation
- $V_{DD}$  range from 2.5 to 3.3V
- 1:10 fanout
- Drives either a 50-ohm or 75-ohm transmission line
- Over voltage tolerant input hot swappable
- Low input capacitance
- Low output skew
- Low propagation delay
- Typical ( $t_{pd} < 4$  ns)
- High-speed operation > 200 MHz
- LVTTL-/LVC MOS-compatible input
  - Output disable to three-state
- Industrial versions available
- Packages available include: SOIC/SSOP

### Description

The Cypress series of network circuits is produced using advanced 0.35-micron CMOS technology, achieving the industries fastest logic and buffers.

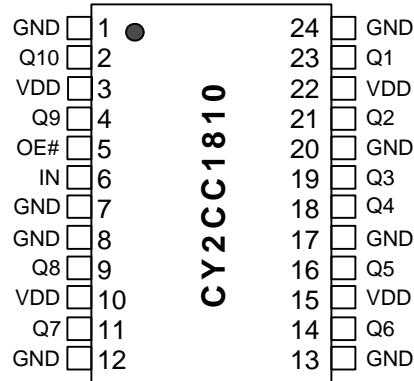
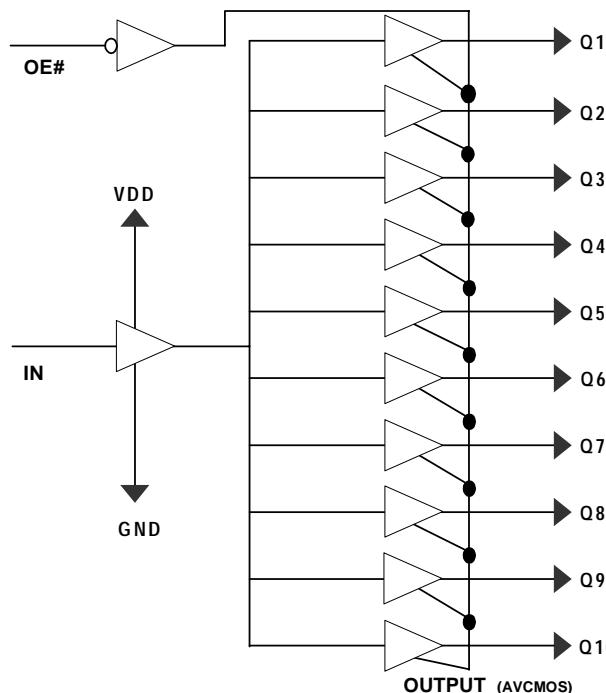
The Cypress CY2CC1810 fanout buffer features one input and ten three-state outputs.

Designed for data communications clock management applications, the large fanout from a single input reduces loading on the input clock.

AVCMOS-type outputs dynamically adjust for variable impedance-matching and eliminate the need for series-damping resistors; they also reduce noise overall.

### Block Diagram

### Pin Configuration



24 pin SOIC/SSOP

### Pin Description

Pin Number	Pin Name	Pin Description	
1,7,8,12,13,17,20,24	GND	Ground	Power
3,10,15,22	V <sub>DD</sub>	Power Supply	Power
5	OE#	Output Enable	LVTTL/LVC MOS
6	IN	Input	LVTTL/LVC MOS
2,4,9,11,14,16,18,19,21,23	Q10.....Q1	Output	AVCMOS

**Maximum Ratings<sup>[1][2]</sup>**

Storage Temperature:	.....	−65°C to + 150°C	Supply Voltage to Ground Potential
Ambient Temperature:	.....	−40°C to +85°C	(Outputs only) ..... −0.5V to $V_{DD}$ + 0.5V
Supply Voltage to Ground Potential			DC Output Voltage ..... −0.5V to $V_{DD}$ + 0.5V
$V_{CC}$	.....	−0.5V to 4.6V	Power Dissipation ..... 0.75W
Input	.....	−0.5V to 5.8V	

**DC Parameter @ 3.3V  $V_{DD}$  = 3.3V ± 5%,  $T_A$  = −40°C to +85°C (see Figure 6)**

Parameter	Description	Conditions		Min.	Typ.	Max.	Unit
$V_{OH}$	Output High Voltage	$V_{DD}$ = Min., $V_{IN}$ = $V_{IH}$ or $V_{IL}$	$I_{OH}$ = −12 mA	2.3	3.3		V
$V_{OL}$	Output Low Voltage	$V_{DD}$ = Min., $V_{IN}$ = $V_{IH}$ or $V_{IL}$	$I_{OL}$ = 12 mA		0.2	0.5	V
$V_{IH}$	Input High Voltage	Guaranteed Logic High Level		2		5.8	V
$V_{IL}$	Input Low Voltage	Guaranteed Logic Low Level				0.8	V
$I_{IH}$	Input High Current	$V_{DD}$ = Max.	$V_{IN}$ = 2.7V			1	uA
$I_{IL}$	Input Low Current	$V_{DD}$ = Max.	$V_{IN}$ = 0.5V			−1	uA
$I_I$	Input High Current	$V_{DD}$ = Max., $V_{IN}$ = $V_{DD}$ (Max.)				20	uA
$V_{IK}$	Clamp Diode Voltage	$V_{DD}$ = Min., $I_{IN}$ = −18 mA			−0.7	−1.2	V
$I_{OK}$	Continuous Clamp Current	$V_{DD}$ = Max., $V_{OUT}$ = GND				−50	mA
$O_{OFF}$	Power-down Disable	$V_{DD}$ = GND, $V_{OUT}$ = < 4.5V				100	uA
$V_H$	Input Hysteresis				80		mV

**DC Parameter @ 2.5V  $V_{DD}$  = 2.5V ± 5%,  $T_A$  = −40°C to +85°C (see Figure 1)**

Parameter	Description	Conditions		Min.	Typ.	Max.	Unit
$V_{OH}$	Output High Voltage	$V_{DD}$ = Min., $V_{IN}$ = $V_{IH}$ or $V_{IL}$	$I_{OH}$ = −7 mA	1.8			V
			$I_{OH}$ = 12 mA	1.6			V
$V_{OL}$	Output Low Voltage	$V_{DD}$ = Min., $V_{IN}$ = $V_{IH}$ or $V_{IL}$	$I_{OL}$ = 12 mA			0.65	V
$V_{IH}$	Input High Voltage	Guaranteed Logic High Level		1.6		5.0	V
$V_{IL}$	Input Low Voltage	Guaranteed Logic Low Level				0.8	V
$I_{IH}$	Input High Current	$V_{DD}$ = Max.	$V_{IN}$ = 2.4V			1	uA
$I_{IL}$	Input Low Current	$V_{DD}$ = Max.	$V_{IN}$ = 0.5V			−1	uA
$I_I$	Input High Current	$V_{DD}$ = Max., $V_{IN}$ = $V_{DD}$ (Max.)				20	uA
$V_{IK}$	Clamp Diode Voltage	$V_{DD}$ = Min., $I_{IN}$ = −18 mA			−0.7	−1.2	V
$I_{OK}$	Continuous Clamp Current	$V_{DD}$ = Max., $V_{OUT}$ = GND				−50	mA
$O_{OFF}$	Power-down Disable	$V_{DD}$ = GND, $V_{OUT}$ = < 4.5V				100	uA
$V_H$	Input Hysteresis				80		mV

**Capacitance**

Symbol	Description	Test Conditions	Typ.	Max.	Unit
$C_{IN}$	Input Capacitance	$V_{IN}$ = 0V	2.5		pF
$C_{OUT}$	Output Capacitance	$V_{OUT}$ = 0V	6.5		pF

**Note:**

1. Stresses greater than those listed under absolute maximum ratings may cause permanent damage to the device. This is intended to be a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Multiple Supplies: The voltage on any input or I/O pin cannot exceed the power pin during power-up. Power supply sequencing is NOT required.

**Power Supply Characteristics (See Figure 1)**

Parameter	Description	Test Conditions		Min.	Typ.	Max.	Unit
$\Delta I_{CC}$	Delta $I_{CC}$ Quiescent Power Supply Current	$(I_{DD} @ V_{DD} = \text{Max. and } V_{IN} = V_{DD}) - (I_{DD} @ V_{DD} = \text{Max. and } V_{IN} = V_{DD} - 0.6V)$				50	uA
$I_{CCD}$	Dynamic Power Supply Current	$V_{DD} = \text{Max.}$ Input toggling 50% Duty Cycle, Outputs Open	$fL = f_{MAX}$ $OE\# = V_{DD}$			0.63	mA/ MHz
$I_C$	Total Power Supply Current	$V_{DD} = \text{Max.}$ Input toggling 50% Duty Cycle, Outputs Open $fL = 40$ MHz	$fL = 100$ MHz $OE\# = \text{GND}$			25	mA

**High-frequency Parametrics**

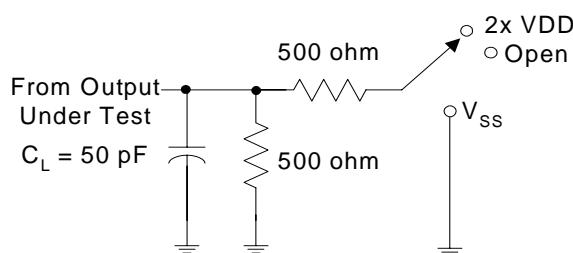
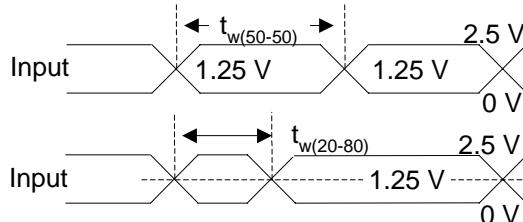
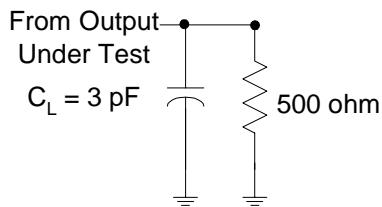
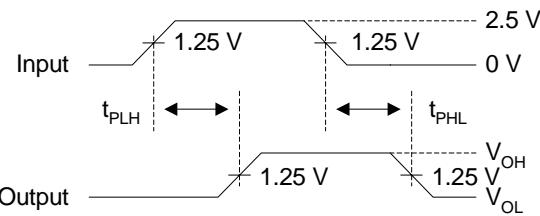
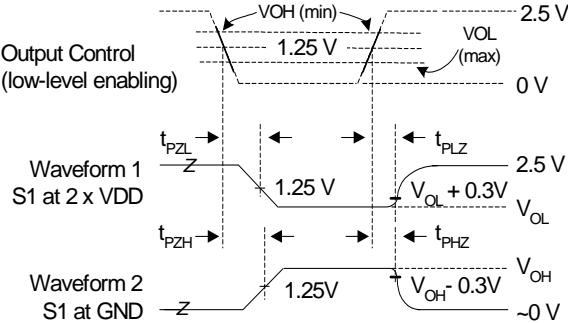
Parameter	Description	Test Conditions		Min.	Typ	Max	Unit	
$D_J$	Jitter, Deterministic	50% duty cycle $t_W(50-50)$ The “point to point load circuit”  Output Jitter – Input Jitter		See Figure 8			20	ps
$F_{max}$	Maximum frequency $V_{DD} = 3.3V$	50% duty cycle $t_W(50-50)$ Standard Load Circuit.		See Figure 6			160	MHz
		50% duty cycle $t_W(50-50)$ The “point to point load circuit”		See Figure 8			200	
$F_{max(20)}$	Maximum frequency $V_{DD} = 3.3 V$	20% duty cycle $t_W(20-80)$ The “point to point load circuit” $V_{IN} = 3.0V/0.0V$ $V_{OUT} = 2.3V/0.4V$		See Figure 8			200	MHz
	Maximum frequency $V_{DD} = 2.5 V$	The “point to point load circuit” $V_{IN} = 2.4V/0.0V$ $V_{OUT} = 1.7V/0.7V$		See Figure 3			100	
$t_W$	Minimum pulse $V_{DD} = 3.3 V$	The “point to point load circuit” $V_{IN} = 3.0V/0.0V$ $F = 100$ MHz $V_{OUT} = 2.0V/0.8V$		See Figure 7	2			ns
	Minimum pulse $V_{DD} = 2.5 V$	The “point to point load circuit” $V_{IN} = 2.4V/0.0V$ $F = 100$ MHz $V_{OUT} = 1.7V/0.7V$		See Figure 2	1			

**AC Switching Characteristics @ 3.3V  $V_{DD} = 3.3V \pm 5\%$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  (See Figure 6)**

Parameter	Description		Min.	Typ.	Max.	Unit
$t_{PLH}$	Propagation Delay – Low to High	See Figure 9	1.5	3	3.9	ns
$t_{PHL}$	Propagation Delay – High to Low		1.5	3	3.9	ns
$t_{PHZ}$	Propagation Delay – High to High Z	See Figure 10		4		ns
$t_{PLZ}$	Propagation Delay – Low to High Z			3		ns
$t_R$	Output Rise Time	See Figure 9		0.8		V/ns
$t_F$	Output Fall Time			0.8		V/ns
$t_{SK(0)}$	Output Skew: Skew between outputs of the same package (in phase)	See Figure 12			0.2	ns
$t_{SK(p)}$	Pulse Skew: Skew between opposite transitions of the same output ( $t_{PHL} - t_{PLH}$ )	See Figure 11			0.2	ns
$t_{SK(t)}$	Package Skew: Skew between outputs of different packages at the same power supply voltage, temperature and package type.	See Figure 13			0.3	ns
$t_{OFF}$	Delay from OE to Driver Off				4.0	ns
$t_{ON}$	Delay from OE to Driver on				4.0	ns

**AC Switching Characteristics @ 2.5V  $V_{DD} = 2.5V \pm 5\%$ ,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$  (See Figure 1)**

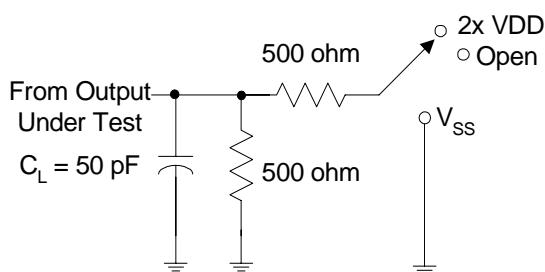
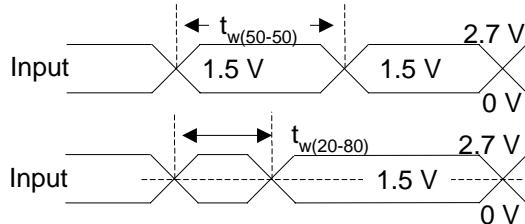
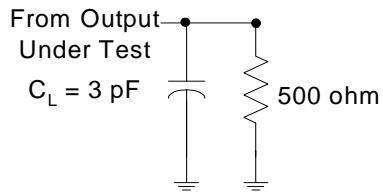
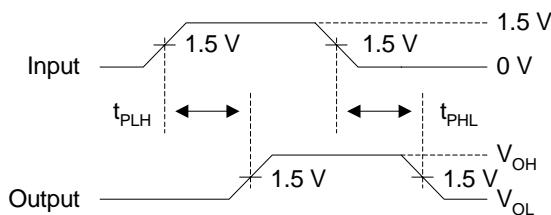
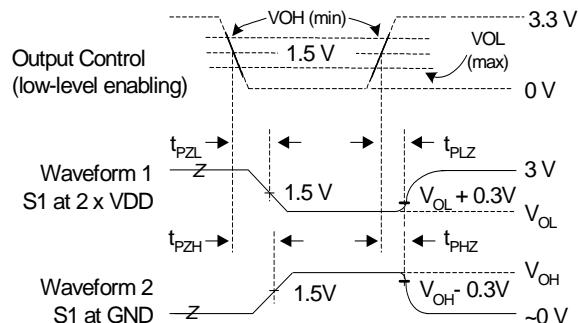
Parameter	Description	Min.	Typ.	Max.	Unit
$t_{PLH}$	Propagation Delay – Low to High	See Figure 4	1.5	3.8	3.5 nS
$t_{PHL}$	Propagation Delay – High to Low		1.5	3.8	3.5 nS
$t_{PHZ}$	Propagation Delay – High to High Z	See Figure 5	5		nS
$t_{PLZ}$	Propagation Delay – Low to High Z		4		nS
$t_R$	Output Rise Time	See Figure 4	0.4		V/nS
$t_F$	Output Fall Time		0.6		V/nS
$t_{SK(0)}$	Output Skew: Skew between outputs of the same package (in phase)	See Figure 12		0.2	nS
$t_{SK(p)}$	Pulse Skew: Skew between opposite transitions of the same output ( $t_{PHL} - t_{PLH}$ )	See Figure 11		0.2	nS
$t_{SK(t)}$	Package Skew: Skew between outputs of different packages at the same power supply voltage, temperature and package type.	See Figure 13		0.3	nS
$t_{OFF}$	Delay from OE to Driver Off			5.0	nS
$t_{ON}$	Delay from OE to Driver on			5.0	nS

**Parameter Measurement Information:  $V_{DD}$  @ 2.5V<sup>[3,5,6]</sup>**

**Figure 1. Load Circuit**

**Figure 2. Voltage Waveforms–Pulse Duration**

**Figure 3. Point-to-Point Load Circuit**

**Figure 4. Voltage Waveforms–Propagation Delay Times<sup>[9]</sup>**

**Figure 5. Voltage Waveforms–Enable and Disable Times<sup>[4,7,8]</sup>**
**Table 1.**

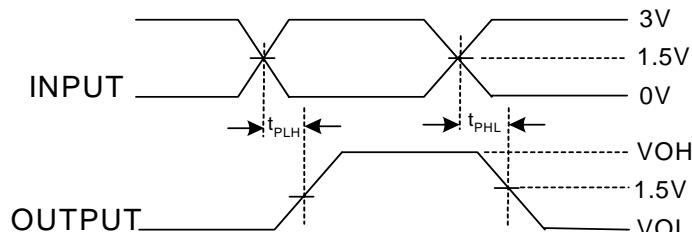
Test	S1	
$t_{PLH}/t_{PHL}$	Open	See Figure 4
$t_{PLZ}/t_{PZH}$	$2 \times V_{DD}$	See Figure 5
$t_{PHZ}/t_{PZH}$	$V_{SS}$	

**Notes:**

3.  $C_L$  includes probe and jig capacitance.
4. Waveform 1 is for an output with internal conditions such that the output is LOW, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the output control.
5. All input pulses are supplied by generators having the following characteristics: PRR < 10 MHz,  $Z_0 = 50\Omega$ ,  $t_R < 2.5$  nS,  $t_F < 2.5$  nS.
6. Outputs are measured one at a time with one transition per measurement.
7.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{PD}$ .
8.  $t_{PZH}$  and  $t_{PZH}$  are the same as  $t_{EN}$ .
9.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .

**Parameter Measurement Information:  $V_{DD}$  @ 3.3V [10,12,13]**

**Figure 6. Load Circuit**

**Figure 7. Voltage Waveforms–Pulse Duration**

**Figure 8. Point-to-Point Load Circuit**

**Figure 9. Voltage Waveforms–Propagation Delay Times<sup>[16]</sup>**

**Figure 10. Voltage Waveforms–Enable and Disable Times<sup>[11,14,15]</sup>**
**Table 2.**

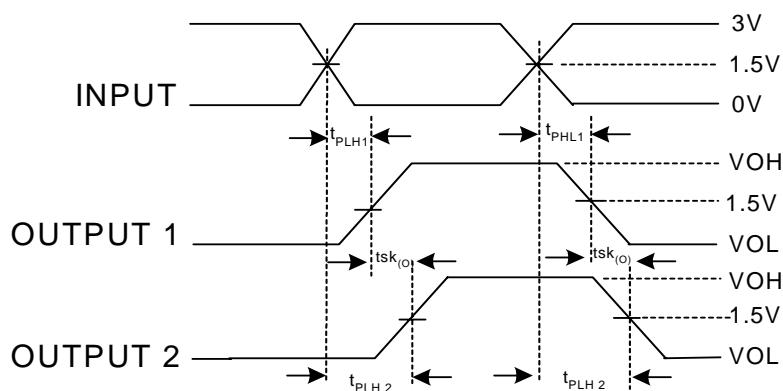
Test	S1	
$t_{PLH}/t_{PHL}$	Open	See Figure 9
$t_{PLZ}/t_{PZL}$	$2 \times VDD$	See Figure 10
$t_{PHZ}/t_{PZH}$	$VSS$	



$$tsk_{(p)} = |t_{PHL} - t_{PLH}|$$

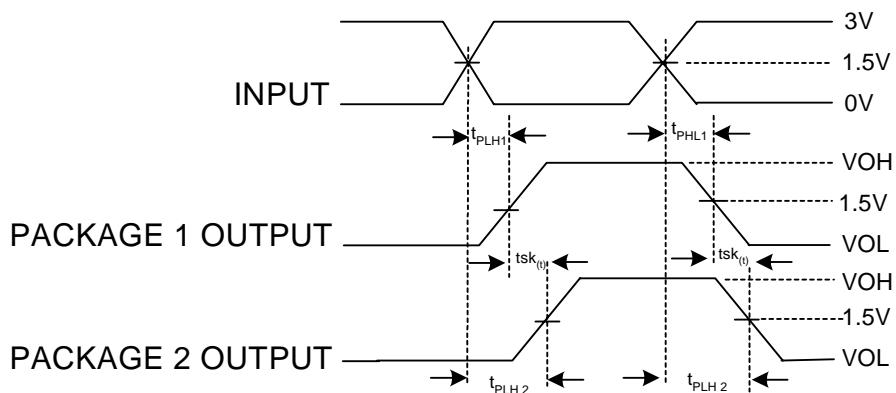
**Figure 11. Pulse Skew–tsk(p)**
**Notes:**

10.  $C_L$  includes probe and jig capacitance
11. Waveform 1 is for an output with internal conditions such that the output is LOW, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is HIGH, except when disabled by the output control.
12. All input pulses are supplied by generators having the following characteristics: PRR < 10 MHz,  $Z_0 = 50\Omega$ ,  $t_R < 2.5 \text{ nS}$ ,  $t_F < 2.5 \text{ nS}$ .
13. The outputs are measured one at a time with one transition per measurement.
14.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{DIS}$ .
15.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{EN}$ .
16.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .



$$tsk_{(P)} = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

**Figure 12. Output Skew- $tsk_{(0)}$**

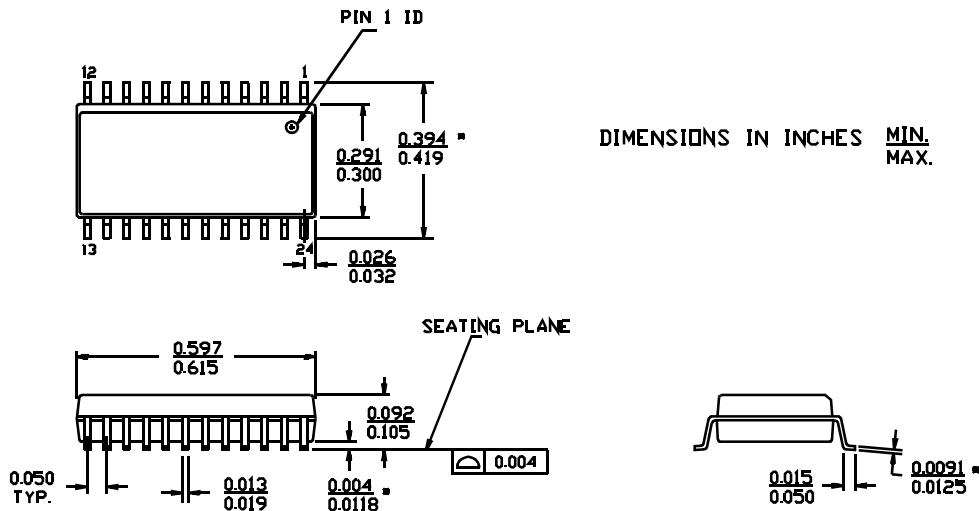
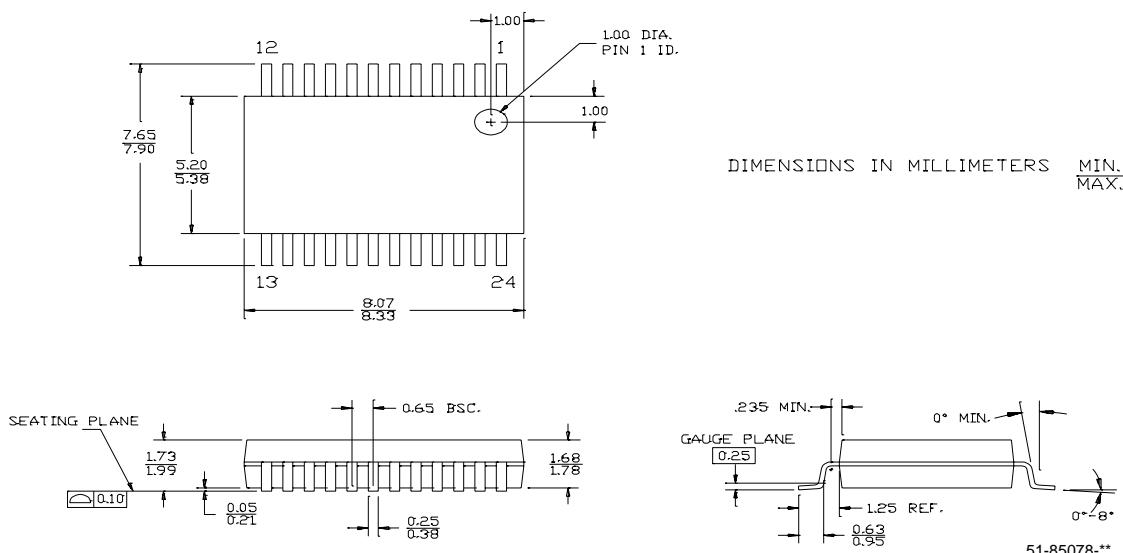


$$tsk_{(t)} = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

**Figure 13. Package Skew -  $tsk_{(t)}$**

### Ordering Information

Part Number	Package Type	Product Flow
CY2CC1810SI	24-pin SOIC	Industrial, -40° to 85°C
CY2CC1810SIT	24-pin SOIC-Tape and Reel	Industrial, -40° to 85°C
CY2CC1810OI	24-pin SSOP	Industrial, -40° to 85°C
CY2CC1810OIT	24-pin SSOP-Tape and Reel	Industrial, -40° to 85°C
CY2CC1810SC	24-pin SOIC	Commercial, 0°C to 70°C
CY2CC1810SCT	24-pin SOIC-Tape and Reel	Commercial, 0°C to 70°C
CY2CC1810OC	24-pin SSOP	Commercial, 0°C to 70°C
CY2CC1810OCT	24-pin SSOP-Tape and Reel	Commercial, 0°C to 70°C

**Package Drawing and Dimensions**
**24-lead (300-mil) Molded SOIC S13**

**24-lead (5.3-mm) Shrunk Small Outline Package O24**


All product and company names mentioned in this document are the trademarks of their respective holders.

**Document History Page**

<b>Document Title: CY2CC1810 1:10 Clock Fanout Buffer with Output Enable</b>				
<b>Document #: 38-07055</b>				
<b>REV.</b>	<b>ECN NO.</b>	<b>Issue Date</b>	<b>Orig. of Change</b>	<b>Description of Change</b>

<b>REV.</b>	<b>ECN NO.</b>	<b>Issue Date</b>	<b>Orig. of Change</b>	<b>Description of Change</b>
**	107080	06/07/01	IKA	Convert from IMI to Cypress format
*A	114316	05/08/02	TSM	$\Delta I_{DD}$ validation
*B	119147	10/07/02	RGL	Added 5.8 as the Max. value for VIH in the DC Parameters @3.3V table. Changed the Max. value of the VIH from 5.8 to 5.0 in the DC Parameters @2.5V table.
*C	122742	12/14/02	RBI	Added power up requirements to maximum ratings information.